# Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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# RENESAS

# RQJ0601DGDQS

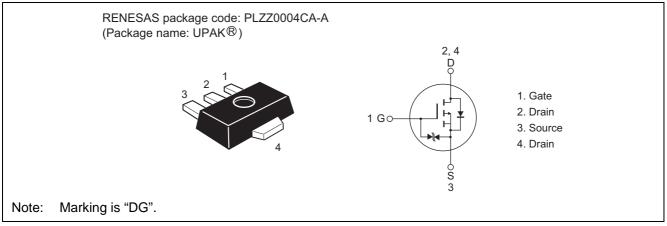
Silicon P Channel MOS FET Power Switching

> REJ03G1266-0300 Rev.3.00 Jun 05, 2006

### Features

- Low on-resistance  $R_{DS(on)} = 124 \text{ m}\Omega \text{ typ} (V_{GS} = -10 \text{ V}, I_D = -1.4 \text{ A})$
- Low drive current
- High speed switching
- 4.5 V gate drive

### Outline



\*UPAK is a trademark of Renesas Technology Corp.

### **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	-60	V
Gate to source voltage	V <sub>GSS</sub>	+10 / -20	V
Drain current	ID	-2.8	А
Drain peak current	Note1 I <sub>D (pulse)</sub>	-4.2	А
Body - drain diode reverse drain current	I <sub>DR</sub>	-2.8	А
Channel dissipation	Pch <sup>Note2</sup>	1.5	W
Channel dissipation	Pch (pulse) Note1	5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1.  $PW \le 1 \text{ s}$ , duty cycle  $\le 1\%$ 

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)



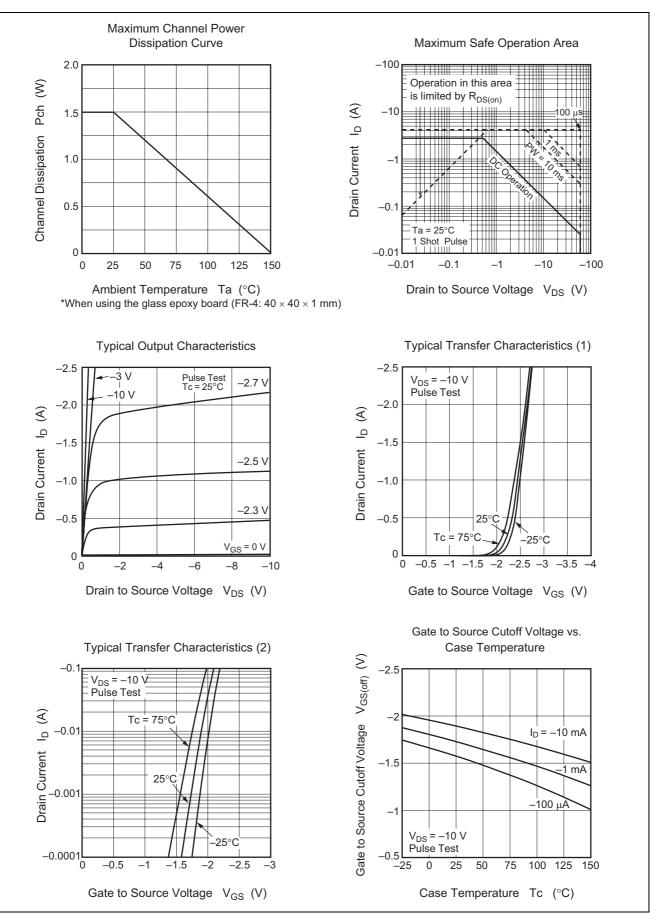
## **Electrical Characteristics**

Item	Symbol	Min	Тур	Max	Unit	Test conditions	
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	-60	_		V	$I_D = -10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	+10	_		V	$I_{G} = +100 \ \mu A, V_{DS} = 0$	
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	-20			V	$I_G = -100 \ \mu A, V_{DS} = 0$	
Gate to source leak current	I <sub>GSS</sub>	_	_	+10	μΑ	$V_{GS} = +8 V, V_{DS} = 0$	
Gate to source leak current	I <sub>GSS</sub>	_	_	-10	μΑ	$V_{GS} = -16 V, V_{DS} = 0$	
Drain to source leak current	I <sub>DSS</sub>	_	_	-1	μΑ	$V_{DS} = -60 \text{ V}, \text{ V}_{GS} = 0$	
Gate to source cutoff voltage	V <sub>GS(off)</sub>	-1.0	_	-2.0	V	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$	
Drain to source on state resistance	R <sub>DS(on)</sub>		124	155	mΩ	$I_D = -1.4 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note3}}$	
	R <sub>DS(on)</sub>		150	210	mΩ	$I_D = -1.4 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note3}}$	
Forward transfer admittance	y <sub>fs</sub>	2.5	4.1	_	S	$I_D = -1.4 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note3}}$	
Input capacitance	Ciss	_	590	—	pF	$V_{DS} = -10 V, V_{GS} = 0,$ f = 1 MHz	
Output capacitance	Coss	_	75	—	pF		
Reverse transfer capacitance	Crss	_	36	_	pF		
Turn - on delay time	t <sub>d(on)</sub>		20		ns	$I_D = -1 \text{ A}, V_{GS} = -10 \text{ V},$	
Rise time	tr		41		ns	$R_L = 10 \Omega$ , $Rg = 4.7 \Omega$	
Turn - off delay time	t <sub>d(off)</sub>		43	_	ns		
Fall time	t <sub>f</sub>		78	_	ns		
Total gate charge	Qg	_	9.6	—	nC	$V_{DD} = -10 \text{ V}, \text{ V}_{GS} = -10 \text{ V},$	
Gate to source charge	Qgs		1.3		nC	I <sub>D</sub> = -2.8 A	
Gate to drain charge	Qgd	_	1.5		nC	1	
Body - drain diode forward voltage	V <sub>DF</sub>	_	-0.8	—	V	$I_F = -1.5 \text{ A}, V_{GS} = 0^{Note3}$	

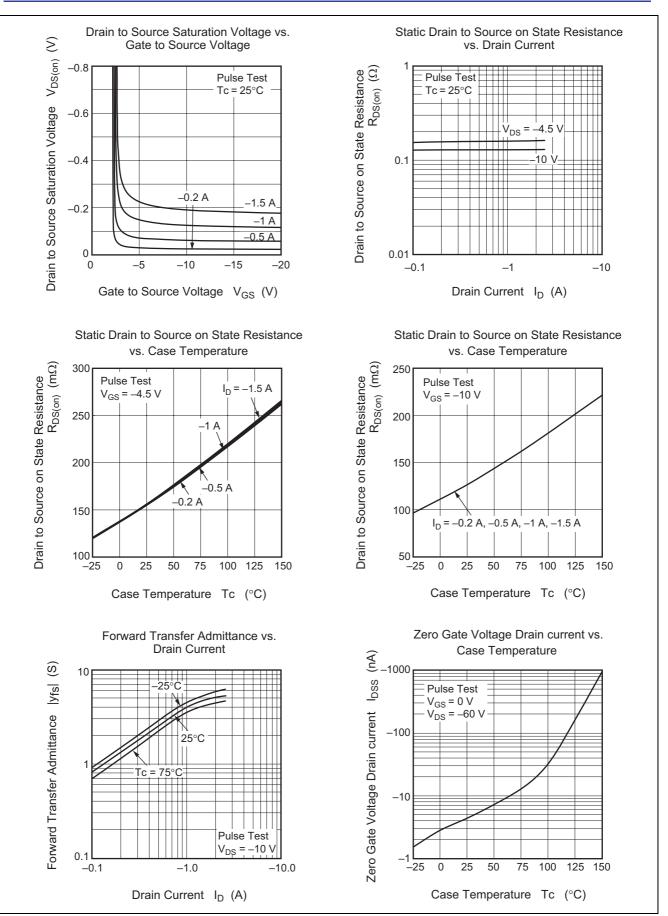
Notes: 3. Pulse test



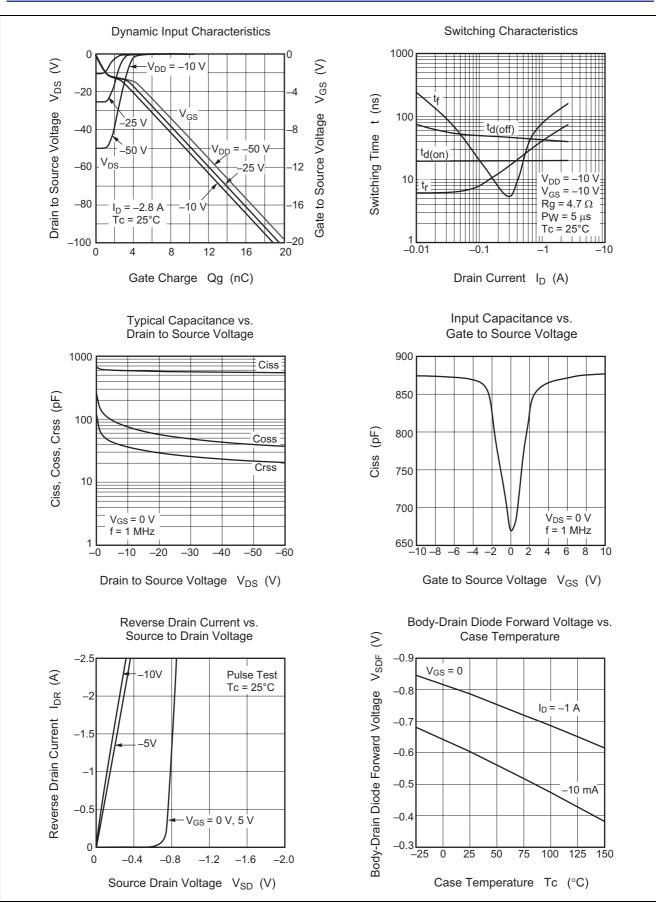
### **Main Characteristics**





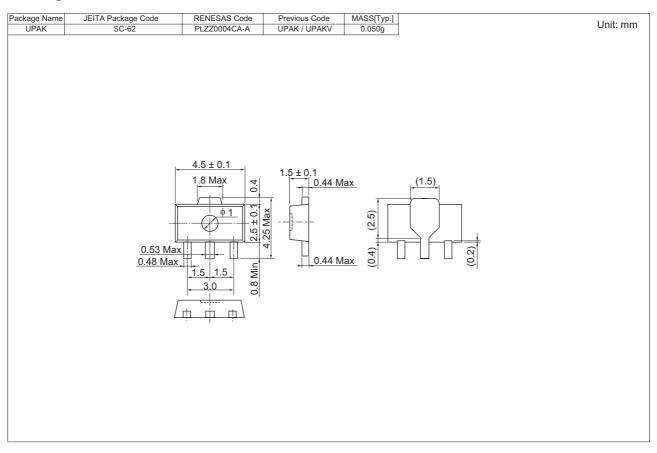








### **Package Dimensions**



# **Ordering Information**

Part Name	Quantity	Shipping Container
RQJ0601DGDQSTL-E	1000 pcs.	φ178 reel, 12 mm Emboss taping



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